

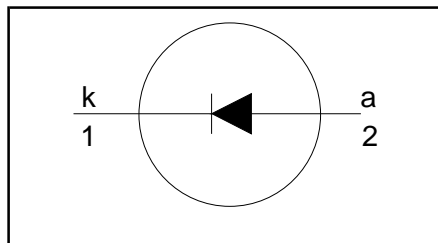
**Rectifier diodes
Schottky barrier**

PBYL2025 series

FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$V_R = 20 \text{ V} / 25 \text{ V}$
$I_{F(AV)} = 20 \text{ A}$
$V_F \leq 0.43 \text{ V}$

GENERAL DESCRIPTION

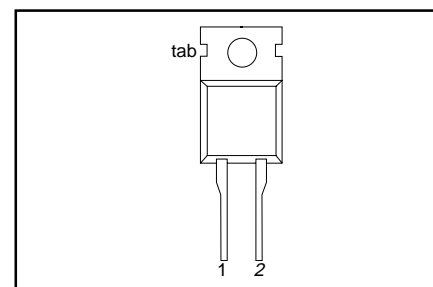
Schottky rectifier diodes intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYL2025 series is supplied in the SOD59 (TO220AC) conventional leaded package.

PINNING

PIN	DESCRIPTION
1	cathode
2	anode
tab	cathode

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V_{RRM}	Peak repetitive reverse voltage	PBYL20 $T_{mb} \leq 120 \text{ }^\circ\text{C}$	-	20 20	25 25	V
V_{RWM}	Working peak reverse voltage		-	20	25	V
V_R	Continuous reverse voltage		-	20	25	V
$I_{F(AV)}$	Average rectified forward current	square wave; $\delta = 0.5$; $T_{mb} \leq 131 \text{ }^\circ\text{C}$	-	20		A
I_{FRM}	Repetitive peak forward current	square wave; $\delta = 0.5$; $T_{mb} \leq 131 \text{ }^\circ\text{C}$	-	40		A
I_{FSM}	Non-repetitive peak forward current	$t = 10 \text{ ms}$	-	180		A
		$t = 8.3 \text{ ms}$	-	200		A
I_{RRM}	Peak repetitive reverse surge current	sinusoidal; $T_j = 125 \text{ }^\circ\text{C}$ prior to surge; with reapplied $V_{RRM(max)}$ pulse width and repetition rate limited by T_{jmax}	-	2		A
T_j	Operating junction temperature		-	150		$^\circ\text{C}$
T_{stg}	Storage temperature		- 65	175		$^\circ\text{C}$

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base	in free air	-	-	1.5	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient		-	60	-	K/W

ELECTRICAL CHARACTERISTICS $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 20\text{ A}; T_j = 150\text{ }^\circ\text{C}$	-	0.36	0.43	V
		$I_F = 20\text{ A}; T_j = 125\text{ }^\circ\text{C}$	-	0.39	0.45	V
		$I_F = 40\text{ A}; T_j = 125\text{ }^\circ\text{C}$	-	0.55	0.62	V
		$I_F = 40\text{ A}$	-	0.59	0.65	V
I_R	Reverse current	$V_R = V_{RWM}$	-	0.4	10	mA
		$V_R = V_{RWM}^2; T_j = 100\text{ }^\circ\text{C}$	-	30	60	mA
C_d	Junction capacitance	$V_R = 5\text{ V}; f = 1\text{ MHz}; T_j = 25\text{ }^\circ\text{C to } 125\text{ }^\circ\text{C}$	-	1230	-	pF

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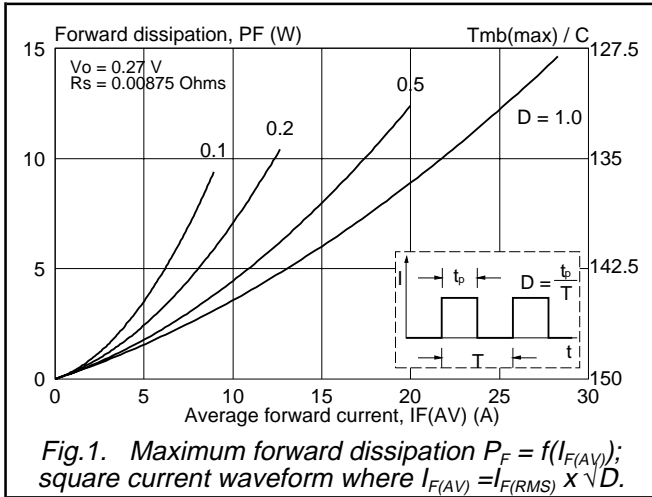


Fig.1. Maximum forward dissipation $P_F = f(I_{F(AV)})$; square current waveform where $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$.

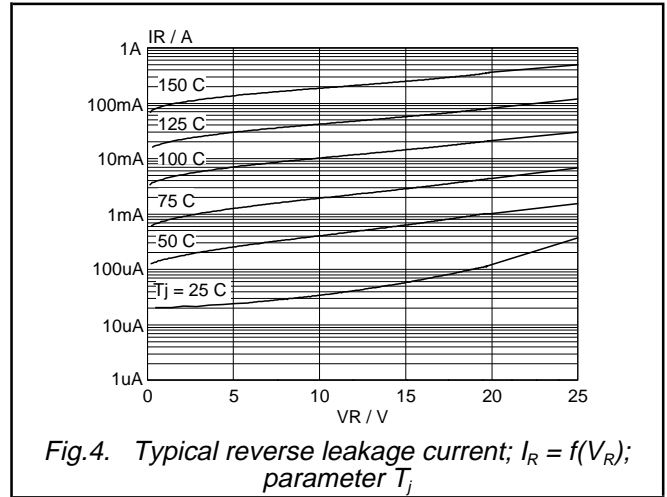


Fig.4. Typical reverse leakage current; $I_R = f(V_R)$; parameter T_j

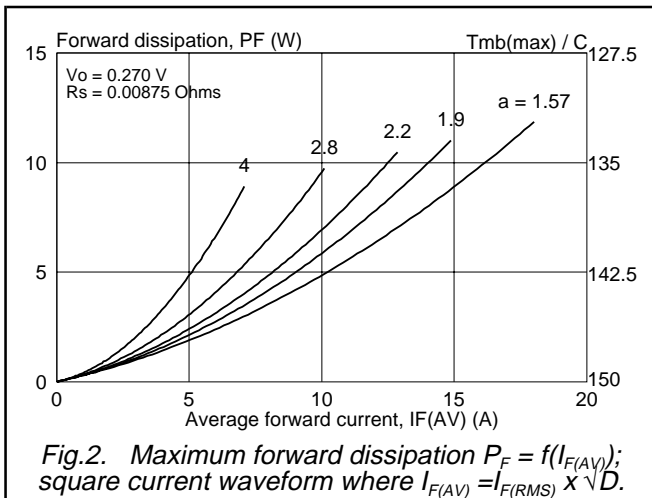


Fig.2. Maximum forward dissipation $P_F = f(I_{F(AV)})$; square current waveform where $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$.

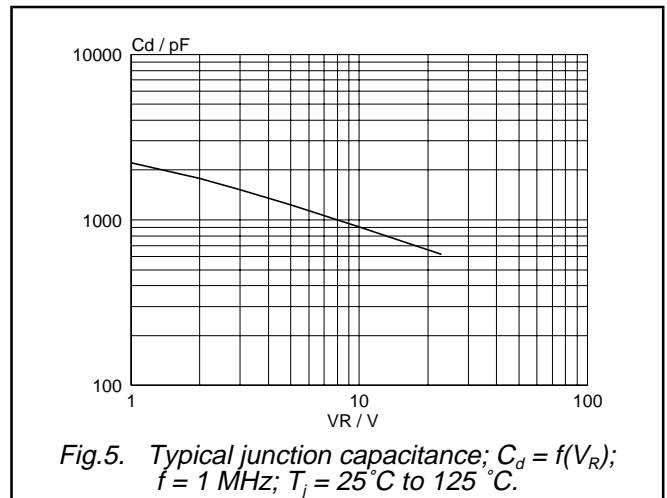


Fig.5. Typical junction capacitance; $C_d = f(V_R)$; $f = 1 \text{ MHz}$; $T_j = 25^\circ C \text{ to } 125^\circ C$.

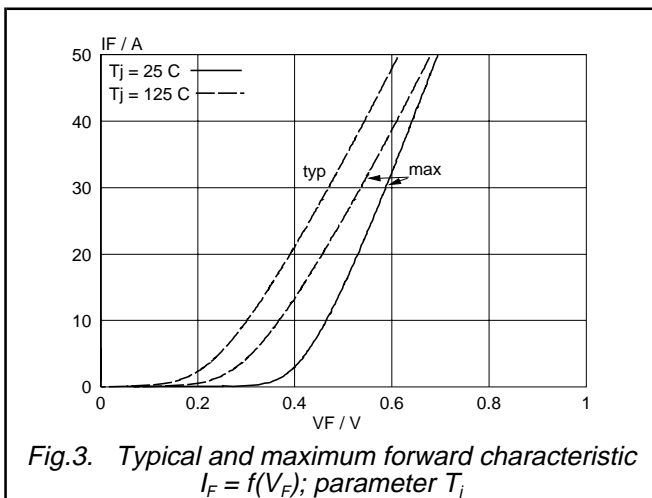


Fig.3. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

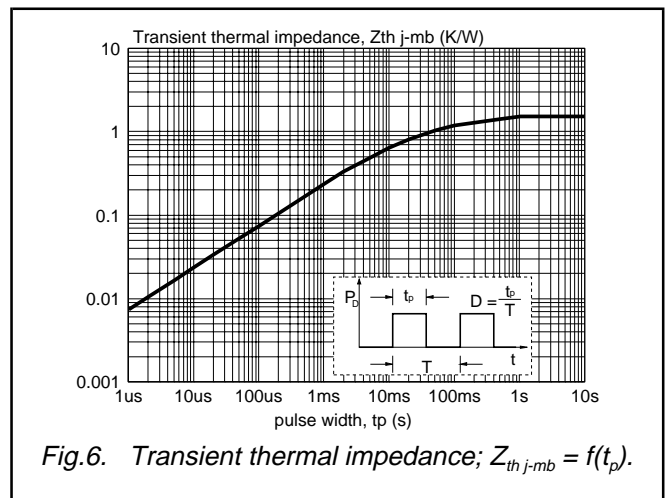
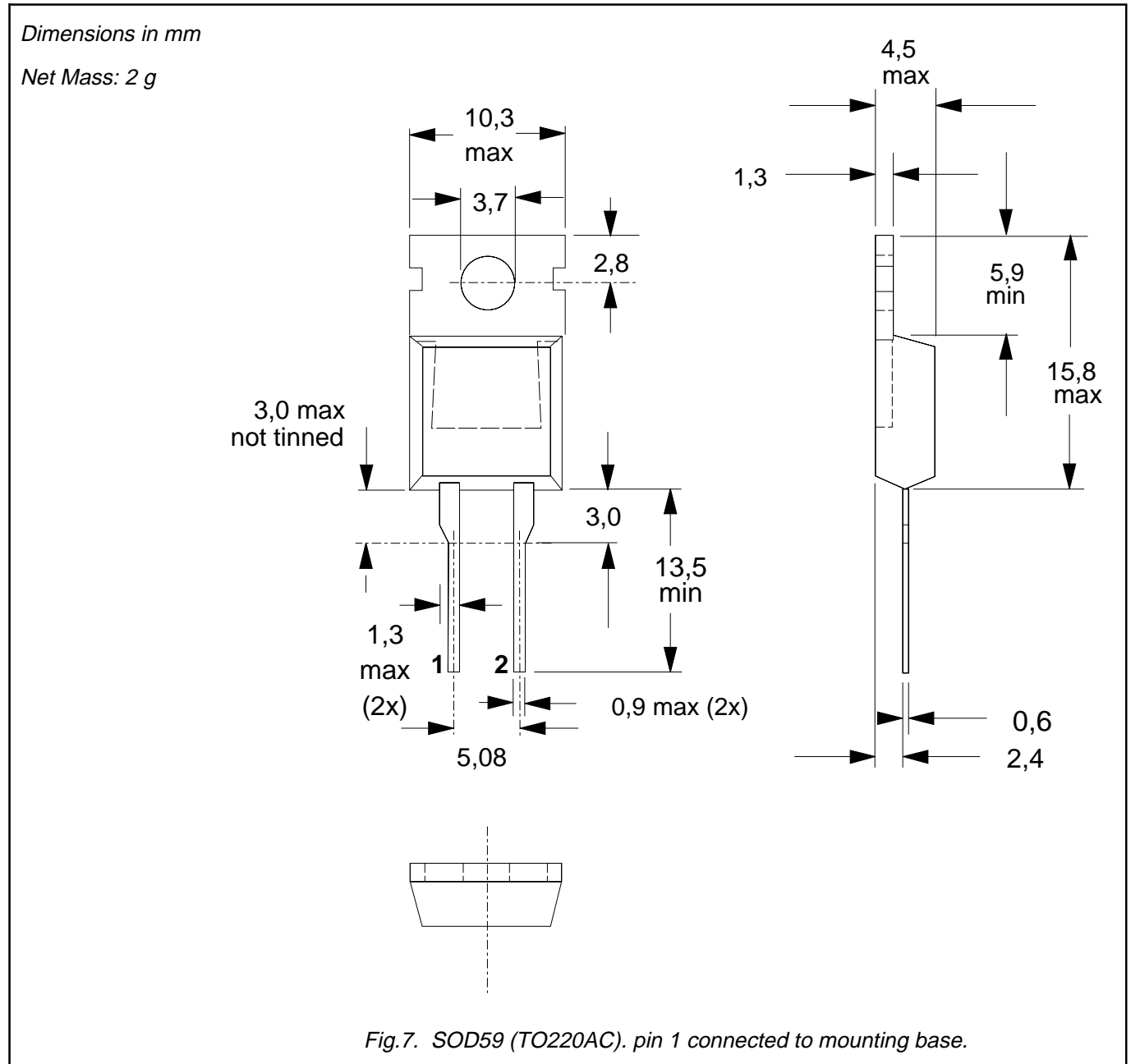


Fig.6. Transient thermal impedance; $Z_{th \text{ j-mb}} = f(t_p)$.

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MECHANICAL DATA



Notes

1. Refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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